

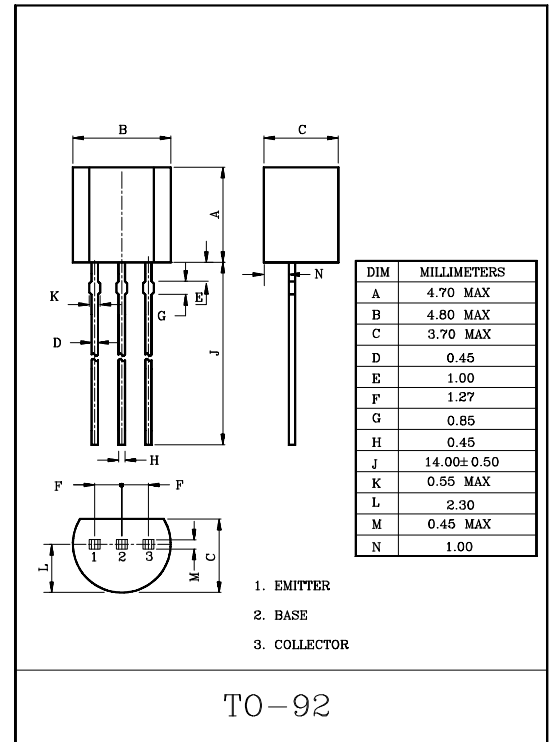
HIGH CURRENT APPLICATION.

### FEATURE

- Complementary to KTC8050.

### MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	-35	V
Collector-Emitter Voltage	$V_{CEO}$	-30	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current	$I_C$	-800	mA
Emitter Current	$I_E$	800	mA
Collector Power Dissipation	$P_C$	625	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{stg}$	-55~150	°C



### ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=-15V, I_E=0$	-	-	-50	nA
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-0.5mA, I_E=0$	-35	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-1mA, I_B=0$	-30	-	-	V
DC Current Gain	$h_{FE(1)}$ (Note)	$V_{CE}=-1V, I_C=-50mA$	100	-	300	
	$h_{FE(2)}$	$V_{CE}=-1V, I_C=-350mA$	60	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-500mA, I_B=-50mA$	-	-	-0.5	V
Base-Emitter Voltage	$V_{BE}$	$V_{CE}=-1V, I_C=-500mA$	-	-	-1.2	V
Transition Frequency	$f_T$	$V_{CE}=-5V, I_C=-10mA$	-	120	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=-10V, f=1MHz, I_E=0$	-	19	-	pF

Note :  $h_{FE(1)}$  Classification    C : 100~200,    D : 150~300

# KTC8550

